



Docket No.: M4065.0971/P971
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Luan C. Tran

Allowed: September 7, 2004

Application No.: 10/663,710

Confirmation No.: 2238

Filed: September 17, 2003

Art Unit: 2818

For: METHOF OF FORMING DRAM
ACCESS TRANSISTORS (AS
AMENDED)

Examiner: T. T. V. Ho

**COMMENTS ON EXAMINER'S STATEMENT OF REASONS FOR
ALLOWANCE**

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

While Applicant does not disagree with the Examiner's stated reasons for allowance, Applicants notes that the allowed claims define further unique combinations of limitations not found in the prior art. Therefore, the stated reasons for allowance should be interpreted as highlighting only some of the reasons why the claims are allowable.

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As usual, the scope of the claims should be interpreted based on the actual language of the allowed claims, and no further limitation of the claims should be inferred from the Examiner's Statement of Reasons For Allowance.

Dated: December 1, 2004

Respectfully submitted,

By 

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